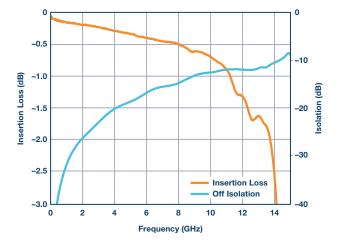


Product Overview

- ► The ADGM1304 and ADGM1004 are single-pole, four-throw (SP4T) switches fabricated using Analog Devices internal microelectromechanical systems (MEMS) switch technology.
- ► This state-of-the-art technology enables a vastly smaller, more reliable, power-saving, lighter, faster switching, and wider bandwidth relay replacement solution.
- ► The ADGM1304 and ADGM1004 are highly linear, low insertion loss switches that are fully operational from 0 Hz/dc up to 14 GHz and 13 GHz, respectively. The ADGM1004 is further optimized with a 2.5 kV HBM ESD rating.
- A copackaged, low voltage, standard logic compatible driver IC generates the high voltage necessary to internally electrostatically actuate the switch. All four switches are also independently controlled for maximum flexibility.

ADGM1304 Insertion Loss and Off Isolation









ADGM1304/ADGM1004 Highlights to Remember



Gold cantilever type designs



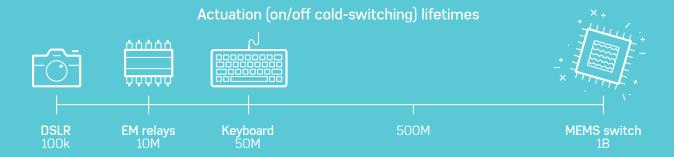
than typical EM relays



in power usage



>20× lighter than typical EM relays



(with no sound)



EMR 1000 µsec



MEMS switch

MEMS contact gap (over 100× less than hair width)

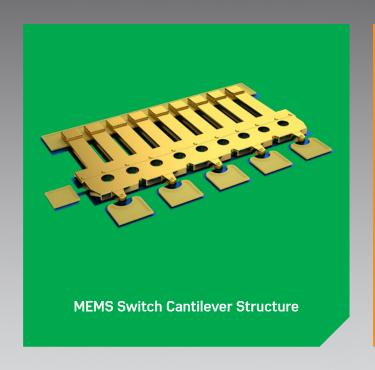


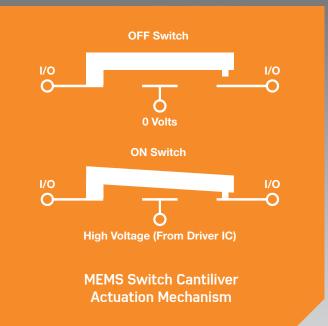


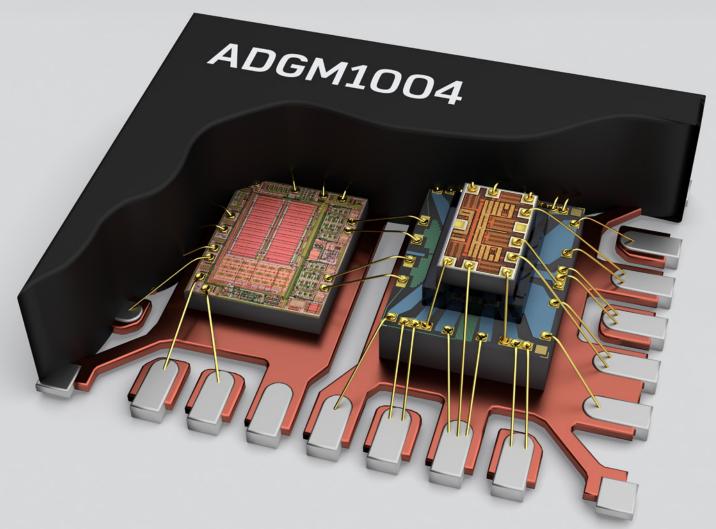
MEMS switch

O Hz/dc to 14 GHz+









ADGM1004 MEMS switch showing inbuilt, low voltage/low power driver on left, MEMS switch on right (SP4T) with mounted, solid-state, 5 kV HBM ESD protection die on RF pins.



Introducing a revolutionary O Hz/dc to GHz switching solution. Innovative thinking and a proprietary approach offer a superior alternative to conventional relay approaches. Discover what MEMS switch technology can do for you in instrumentation, aerospace and defense, health-care, communications, and other key markets.

Visit analog.com/MEMSswitch

User Guides

UG-644: Evaluating the ADGM1304 0 Hz/DC to 14 GHz, Single-Pole, Four-Throw MEMS Switch with Integrated Driver (Rev. A)

Technical Articles

The Fundamentals of Analog Devices' Revolutionary MEMS Switch Technology

Groundbreaking 5 kV ESD MEMS Switch Technology

Circuit Notes

CN-0377: DC to 2.5 GHz Switchable RF Attenuator Implemented with RF MEMS Switches (Rev. A)

Press Release

Analog Devices Makes MEMS Switch Technology a Commercial Reality



ADGM1304/ADGM1004: 5 mm × 4 mm × 0.95 mm/1.45 mm LFCSP.

Pa Ni	art umber	Device Configuration	Switch R _{on} (Typ)(Ω)	Leakage Switch Off (Typ) (pA)	Frequency Response (Min) (Hz)	Frequency Response (Max) (GHz)	Insertion Loss (Typ) (dB)	Off Isolation (Typ) (dB)	IIP3 (Typ) (dBm)	Input Power (Max) (dBm)	Specified at Frequency (GHz)	Price 1000 to 4999 (\$U.S.)
Α[OGM1004	(4:1) × 1	1.8	500	0	13	0.45	24	67	32	2.5	39.34
ΑE	OGM1304	(4:1) × 1	1.6	500	0	14	0.26	24	69	36	2.5	36.58

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